



# Building blocks 0.18 $\mu\text{m}$ XFAB SOI

Calice Meeting - Argonne 2014

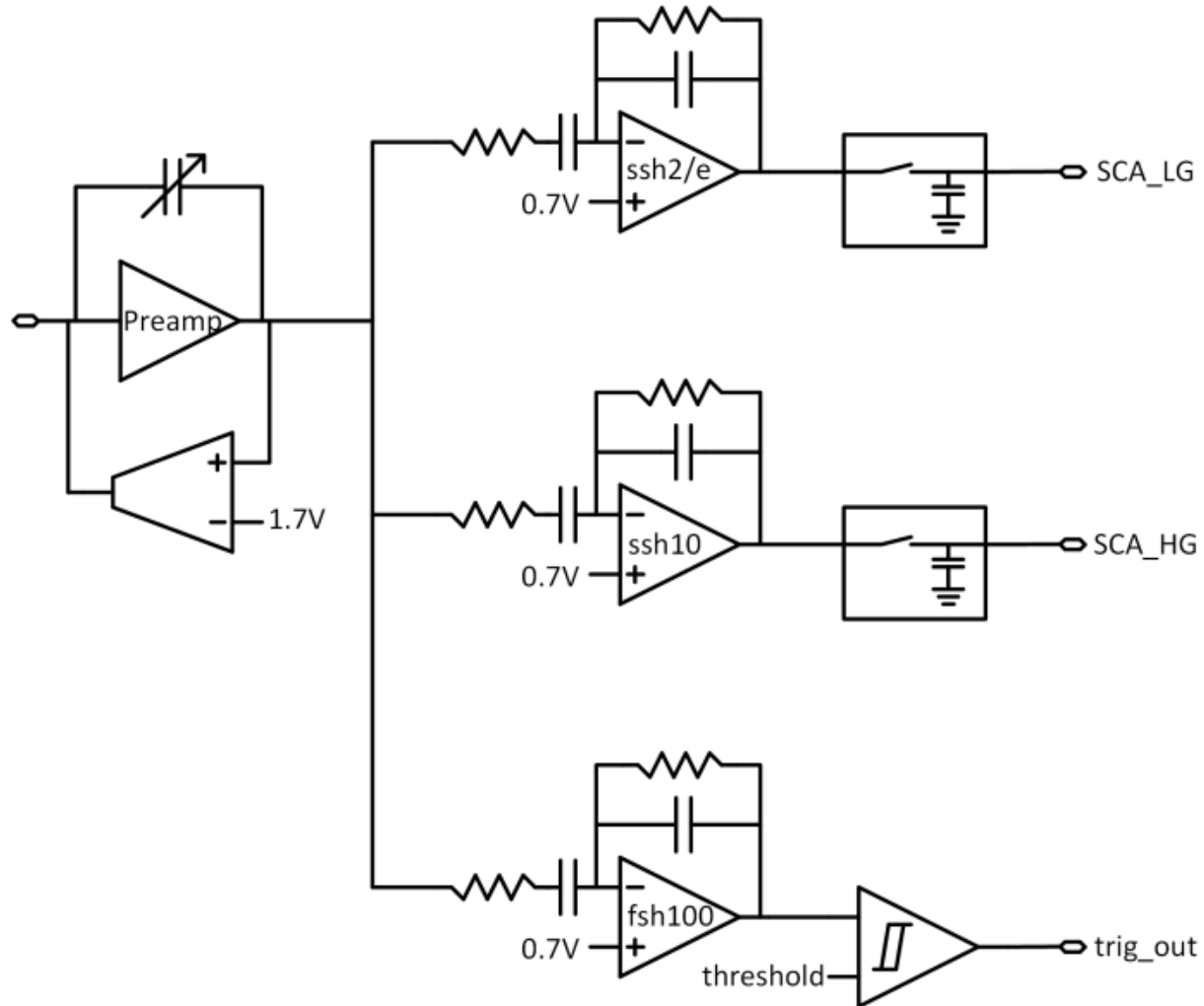


# XFAB SOI 0.18 $\mu\text{m}$

- SOI Silicon On Insulator ;
- Recent technology (2011) ;
- Cheaper than the 0.35  $\mu\text{m}$  AMS technology ;
- Better for digital electronics.

**Disclaimer:** The following is a study for building blocks in this technology, not a chip.

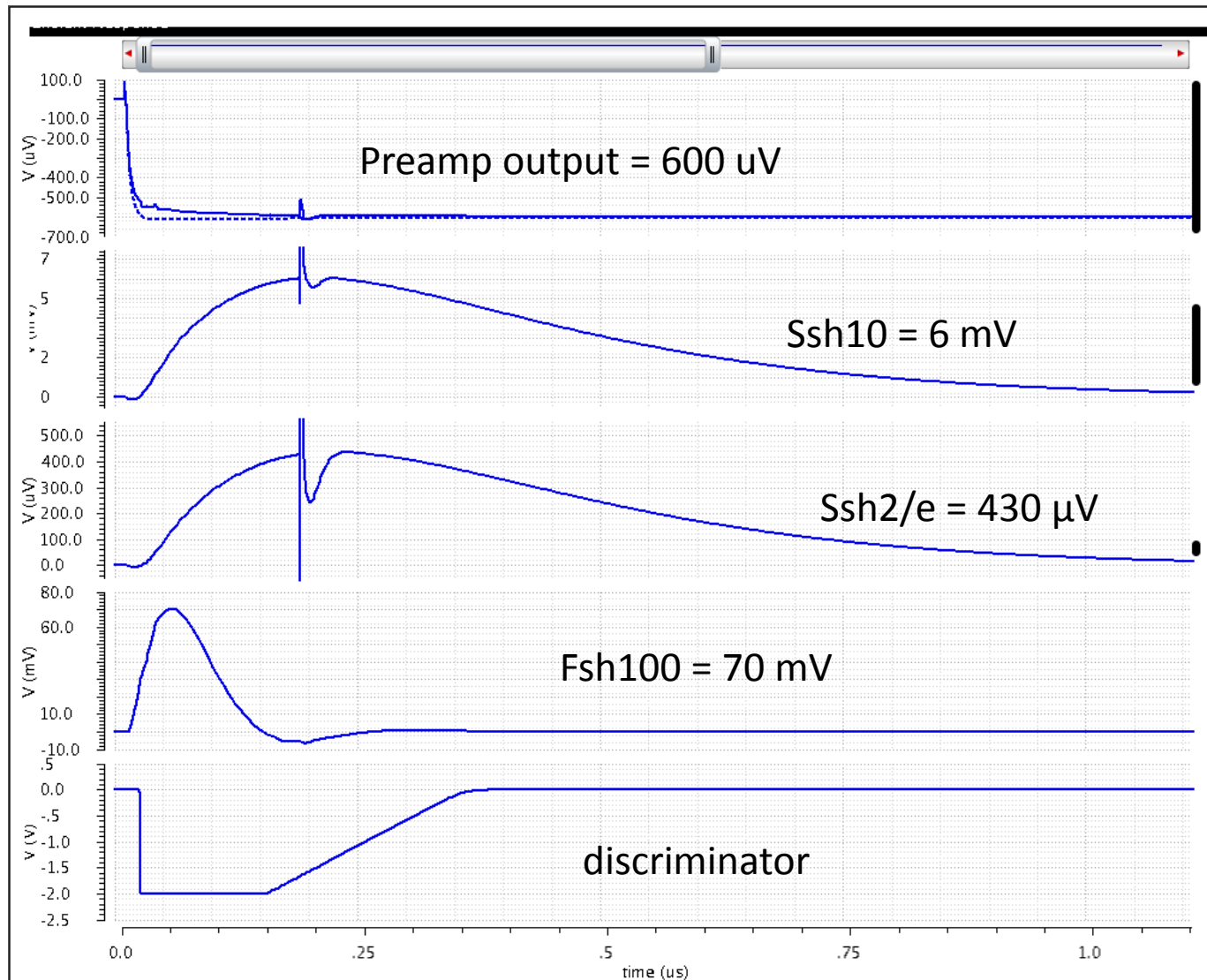
# Simplified schematic



# Specifications

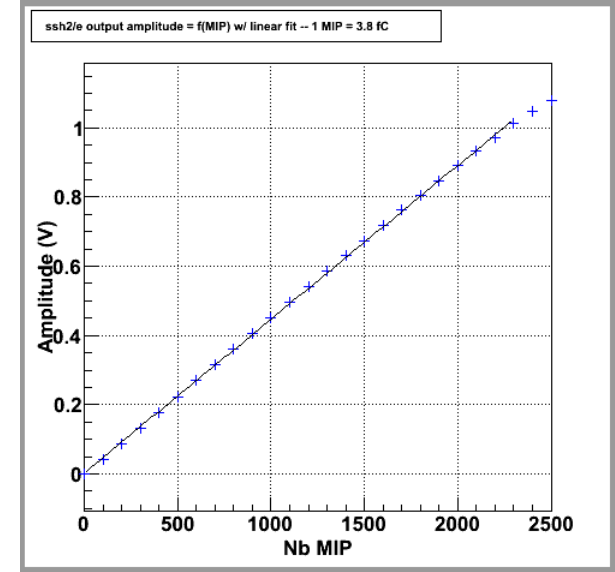
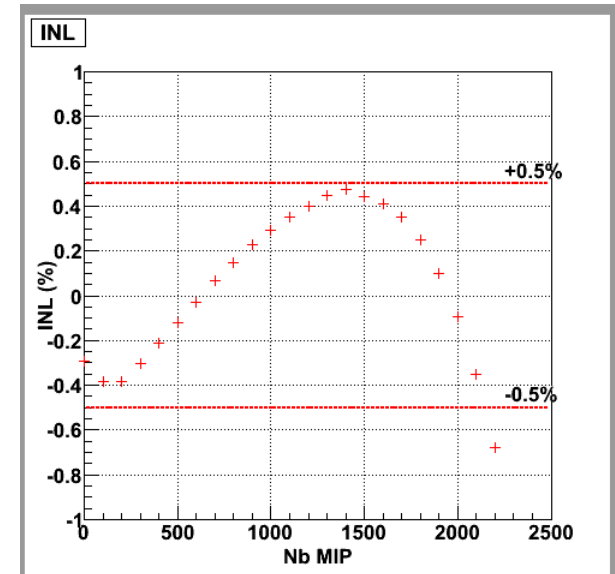
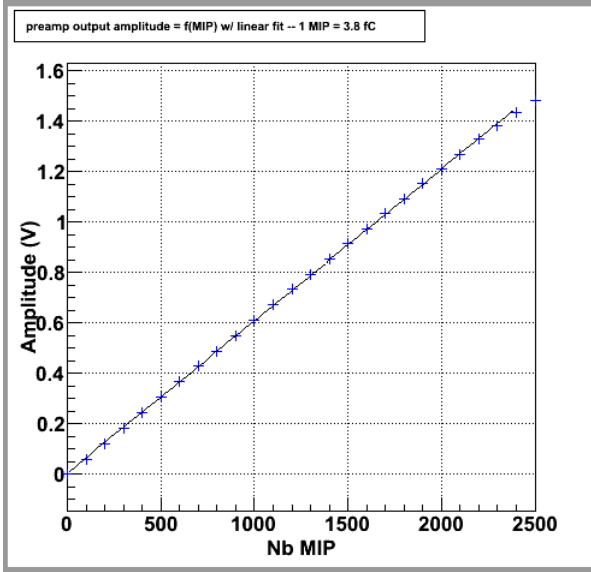
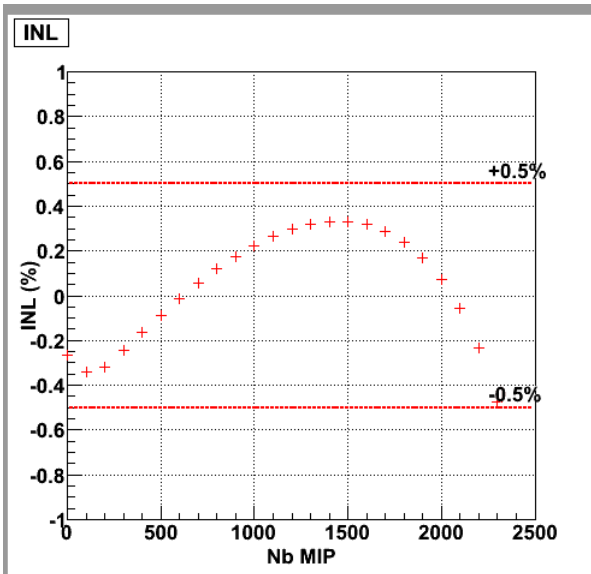
- Adjustable feedback capacitor from 500 fC to 7.5 pC ;
- Slow shapers' shaping time of 180 ns ;
- Fast shaper's shaping time of 30 ns ;
- 2 slow shapers: slow shaper high gain with a gain of 10, slow shaper low gain with a gain of  $2/e$  ( $\approx 0.74$ ) ;
- Fast shaper gain 100 ;
- No fancy adjustable parameters, the building blocks are as simple as it could be, there will be different versions of these ;
- For all the following simulations, the feedback capacitance had been chosen to be 6 pF.

# Analog outputs – simulation results

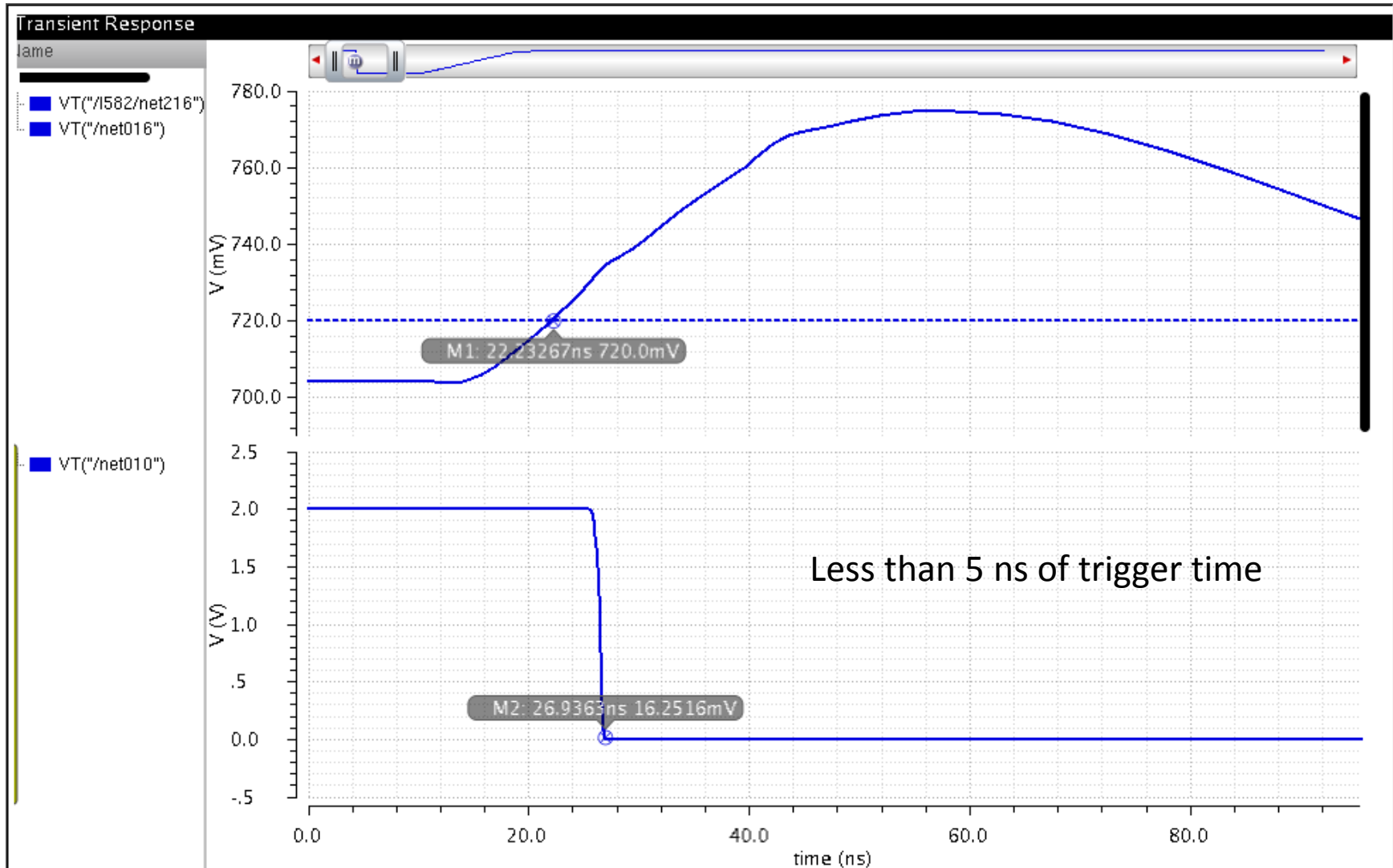


# Linearity

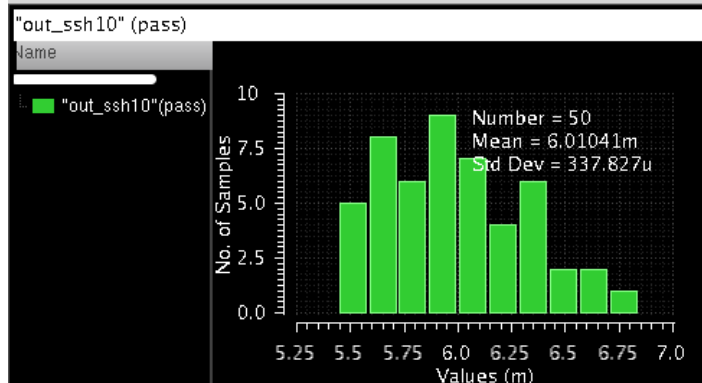
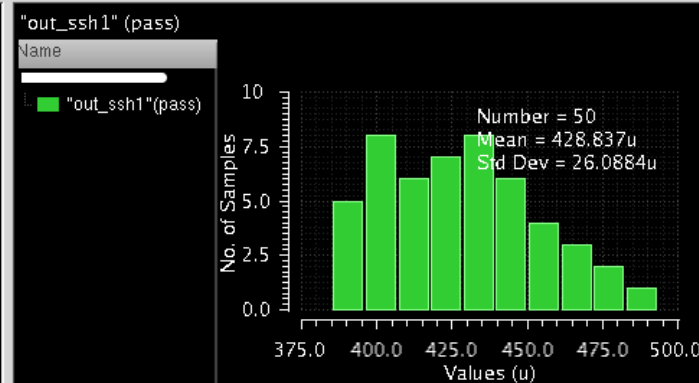
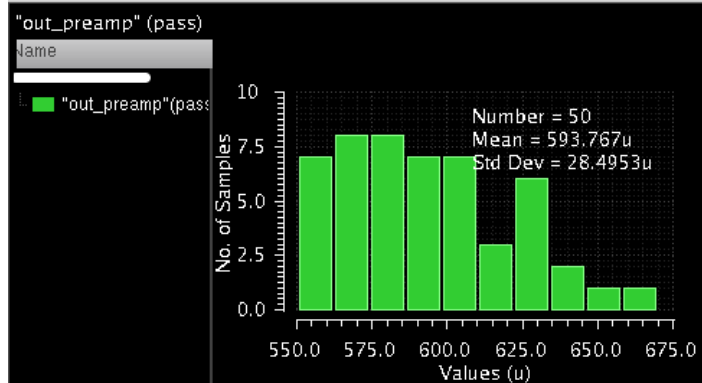
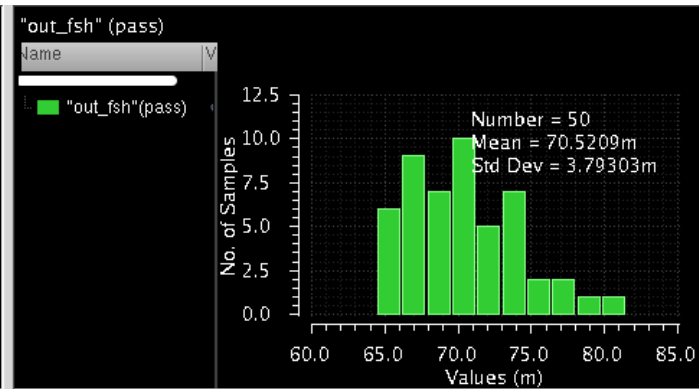
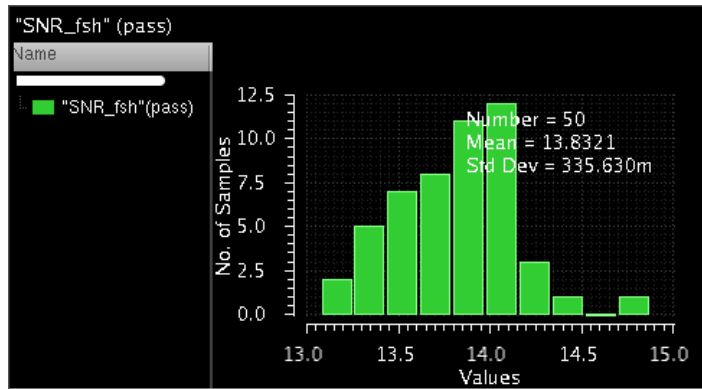
- 1% linearity up to 2300 MIP at preamplifier output and 2200 MIP at low gain slow shaper output.
- 1 MIP = 3.8 fC => 1% linearity up to 8.36 pC (with a 6 pF preamplifier feedback capacitance)



# Discriminator efficiency



# Monte Carlo



The dispersion is mainly due to the feedback capacitance of the preamplifier (+/- 10% accuracy)



# Noise issues

- Noise contributions not understood. (doesn't seem to fit the theory)
- 6 pF doesn't give enough first stage gain to have a nice noise behaviour. 2 pF is preferable but the handled charge range will be reduced.

# Different preamplifier design options

- A Nmos common source was used for these simulations.
- Differential amplifier and Pmos common source have been studied too.
- Differential:
  - Differential preamplifier works well and permits high gain in open loop (2-stages) and so 1/1000 linearity.
  - More noise and consumption.
  - Bigger surface (2 input transistors, adjustable compensation capacitor)
- Pmos common source:
  - Preamplifier architecture of skiroc2.
  - Standard cascode reduces the dynamic range, so folded cascode is used instead, leading in a drop in open loop gain and thus degrading closed loop linearity.
  - Potentially the same issues with power supply than in skiroc2.

# Different building blocks design options

- Bandgap
- Shaper amplifiers
- Analog memories

# Schedule

- Tape-out in May
- Back in october
- First results expected in december
- Possibly a new skiroc prototype on 0.18  $\mu\text{m}$

Thanks for your attention